

FEATURES

- 5V power supply
- Up to 2.5Gbps operation
- 25mA peak drive current
- Separate modulation control
- Separate output enable for laser safety
- Differential inputs for data
- 75K Ω input pulldown resistor
- Designed for use with SY88923, SY88904 or SY88905
- ESD protection of 2000V
- Available in a tiny 10-pin (3mm) TSSOP

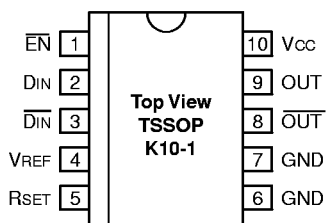
DESCRIPTION

The SY88922 is a high speed current switch for driving a semiconductor laser diode in optical transmission applications. The output current, or modulation current I_{MOD} , is DC current controlled by I_{RSET} , current through the resistor R_{SET} . The output OUT is HIGH when output enable is HIGH.

The device incorporates complementary open collector outputs with a capability of driving peak current of 25mA. The resistor R_{EXT} must be placed between $\overline{OUT}$ and V_{CC} to dissipate the worst case power. R_{SER} is recommended to compensate for laser diode matching issues.

The SY88922 utilizes the high performance bipolar ASSET™ technology.

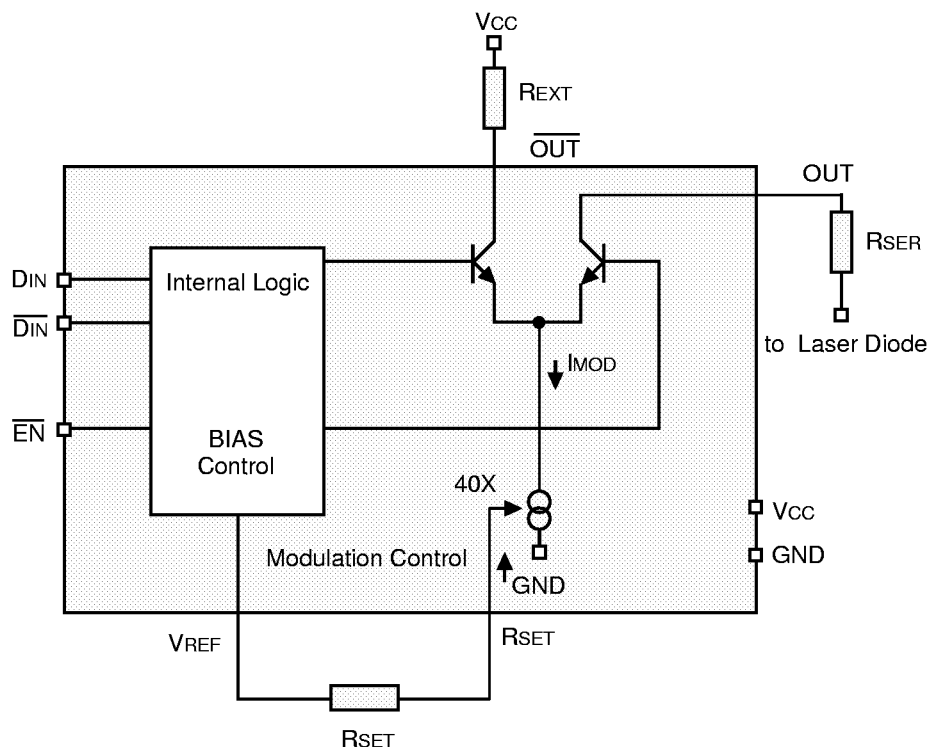
PIN CONFIGURATIONS



APPLICATIONS

- 1.25Gbps Gigabit Ethernet
- 531Mbps and 1062Mbps Fibre Channel
- 622Mbps SONET
- Gigabit Interface Converter
- 2.5Gb/s SDH/SONET

BLOCK DIAGRAM



PIN NAMES

Pin	Function
VCC	Most positive power supply input, +5V for PECL operation.
GND	Ground
DIN, $\overline{\text{DIN}}$	These differential PECL 100K compatible inputs receive NRZ data.
$\overline{\text{EN}}$	This PECL 100K compatible input enables Laser Driver. Modulation current goes to zero when asserted HIGH.
OUT, $\overline{\text{OUT}}$	Open collector outputs from the modulation buffer drive these differential current outputs.
VREF	Voltage reference for use with RSET.
RSET	An external resistor sets up the source current for modulation I_{mod} .

TRUTH TABLE⁽¹⁾

D	$\overline{\text{D}}$	$\overline{\text{EN}}$	OUT ⁽²⁾	$\overline{\text{OUT}}$
L	H	L	H	L
H	L	L	L	H
X	X	H	H	L

NOTES:

1. L = LOW, H = HIGH, X = don't care
2. H = IOUT = 0mA

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Value	Unit
VCC	Power Supply Voltage	0 to +7.0	V
VI	Input Voltage	0 to VCC	V
IO	Output Current	25	mA
TA	Operating Temperature Range	0 to +85	°C
Tstore	Storage Temperature Range	-55 to +125	°C
Ptot	Power Dissipation	250	mW

NOTE:

1. Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to ABSOLUTE MAXIMUM RATING conditions for extended periods may affect device reliability.

OPERATIONING CONDITIONS⁽¹⁾

Symbol	Rating	Value	Unit
VCC	Power Supply Voltage	+4.5 to +5.5	V
REXT	Resistor to Dissipate Power	10 to 50	Ω
RSER	Laser Diode Serial Resistor	0 to 50	Ω
RSET	Resistor to Adjust Current	1500 to 50,000	Ω
Θ_{JA}	Thermal Resistance of Package to Ambient ⁽²⁾	113	°C/W
COUT	Capacitance on OUT + $\overline{\text{OUT}}$	2.5 typical	pf

NOTES:

1. The voltage drop across REXT and RSER plus Laser Diode should not be greater than 2V.
2. Still air without heatsink.

DC ELECTRICAL CHARACTERISTICS

GND = 0V; V_{CC} = +5.0V ±10%; T_A = 0°C to +85°C

Symbol	Parameter	T _A = 0°C			T _A = +25°C			T _A = +85°C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V _{IH}	Input HIGH Voltage (D _{IN} , $\overline{\text{D}}_{\text{IN}}$, EN)	V _{CC} -1165	—	V _{CC} -880	V _{CC} -1165	—	V _{CC} -880	V _{CC} -1165	—	V _{CC} -880	mV
V _{IL}	Input LOW Voltage (D _{IN} , $\overline{\text{D}}_{\text{IN}}$, EN)	V _{CC} -1810	—	V _{CC} -1475	V _{CC} -1810	—	V _{CC} -1475	V _{CC} -1810	—	V _{CC} -1475	mV
V _{REF}	Reference Voltage	—	3.12	—	—	3.00	—	—	2.80	—	V
I _{IL}	Input LOW Current ⁽¹⁾ (D _{IN} , $\overline{\text{D}}_{\text{IN}}$, EN)	0.5	—	—	0.5	—	—	0.5	—	—	μA
I _{IH}	Input HIGH Current (D _{IN} , $\overline{\text{D}}_{\text{IN}}$, EN)	—	—	100	—	—	100	—	—	100	μA
I _{CC}	Supply Current ⁽²⁾	—	16	25	—	16	25	—	16	25	mA
I _{OL}	Output LOW Current (EN = HIGH)	—	—	500	—	—	500	—	—	500	μA
I _{OUT}	Modulation Current	5	15	25	5	15	25	5	15	25	mA
I _{RSET}	Modulation Control	0.125	—	0.625	0.125	—	0.625	0.125	—	0.625	mA
A _{RSET}	=I _{OUT} /I _{RSET}	30	38	44	30	38	44	30	38	44	—

NOTES:

1. V_I = V_{IL}(Min.)

2. I_{MOD} = 25mA.

AC ELECTRICAL CHARACTERISTICS⁽¹⁾

I_{MOD} = 10mA; GND = 0V; V_{CC} = +5V ±10%; T_A = 0°C to +85°C

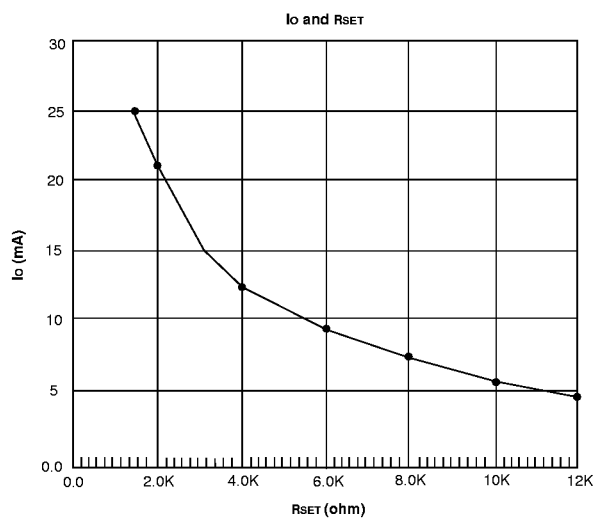
Symbol	Parameter	T _A = 0°C			T _A = +25°C			T _A = +85°C			Unit	Conditions
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
t _{pd D}	Propagation Delay D _{IN} - OUT	—	—	1000	—	500	1000	—	—	1000	ps	
t _{pd EN}	Propagation Delay EN - OUT	—	—	1000	—	450	1000	—	—	1000	ps	
t _r t _f	Rise/Fall Time (20% to 80%)	—	—	160	—	110	160	—	—	160	ps	Load = 25Ω
I _{OR}	Output Current Ringing ⁽²⁾	—	—	10	—	—	10	—	—	10	%	

NOTES:

1. R_{EXT} = R_{SER} = 25Ω ±1%, R_{SER} connects to V_{CC} directly without Laser Diode.

2. I_{OH} = 5 to 25mA

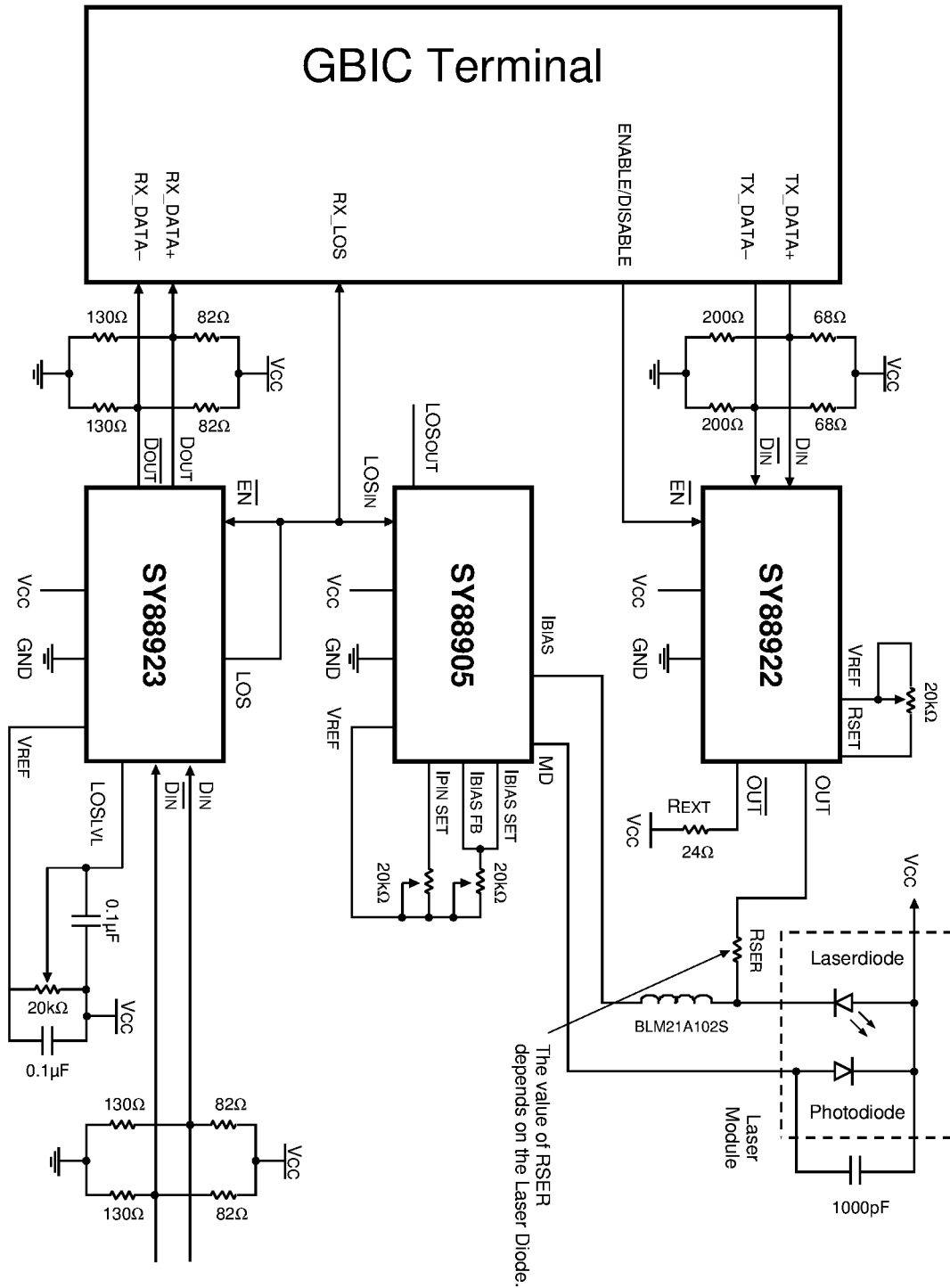
PERFORMANCE CURVES



PRODUCT ORDERING CODE

Ordering Code	Package Type	Operating Range
SY88922KC	K10-1	Commercial
SY88922KCTR	K10-1	Commercial

APPLICATION EXAMPLE FOR 3-CHIP SET SOLUTION



10 LEAD TSSOP (K10-1)

